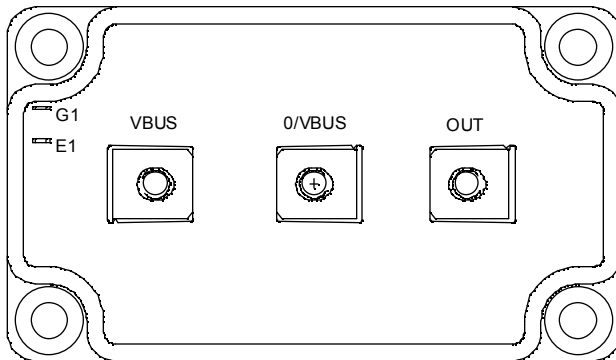
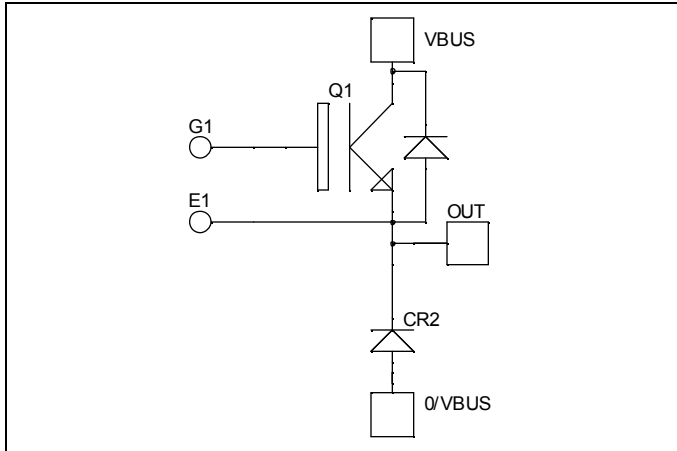


**Buck chopper
Trench + Field Stop IGBT®
Power Module**

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$$V_{CES} = 1700V$$

$$I_C = 225A @ T_c = 80^{\circ}C$$



Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Trench + Field Stop IGBT® Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - Avalanche energy rated
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile

Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage	1700	V
I_C	Continuous Collector Current	$T_c = 25^{\circ}C$	340
		$T_c = 80^{\circ}C$	225
I_{CM}	Pulsed Collector Current	$T_c = 25^{\circ}C$	450
V_{GE}	Gate - Emitter Voltage	± 20	V
P_D	Maximum Power Dissipation	$T_c = 25^{\circ}C$	1250
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	450A @ 1600V

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0\text{V}, V_{CE} = 1700\text{V}$			500	μA
$V_{CE(sat)}$	Collector Emitter Saturation Voltage	$V_{GE} = 15\text{V}$ $I_C = 225\text{A}$	$T_j = 25^\circ\text{C}$	2.0	2.4	V
			$T_j = 125^\circ\text{C}$	2.4		
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 4\text{mA}$	5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20\text{V}, V_{CE} = 0\text{V}$			600	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{ies}	Input Capacitance	$V_{GE} = 0\text{V}$		20		nF
C_{oes}	Output Capacitance	$V_{CE} = 25\text{V}$		0.8		
C_{res}	Reverse Transfer Capacitance	$f = 1\text{MHz}$		0.66		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)		370		ns
T_r	Rise Time	$V_{GE} = 15\text{V}$		40		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 900\text{V}$		650		
T_f	Fall Time	$I_C = 225\text{A}$ $R_G = 3.3\Omega$		180		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C)		400		ns
T_r	Rise Time	$V_{GE} = 15\text{V}$		50		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 900\text{V}$		800		
T_f	Fall Time	$I_C = 225\text{A}$ $R_G = 3.3\Omega$		300		
E_{on}	Turn-on Switching Energy			72		mJ
E_{off}	Turn-off Switching Energy			70.5		

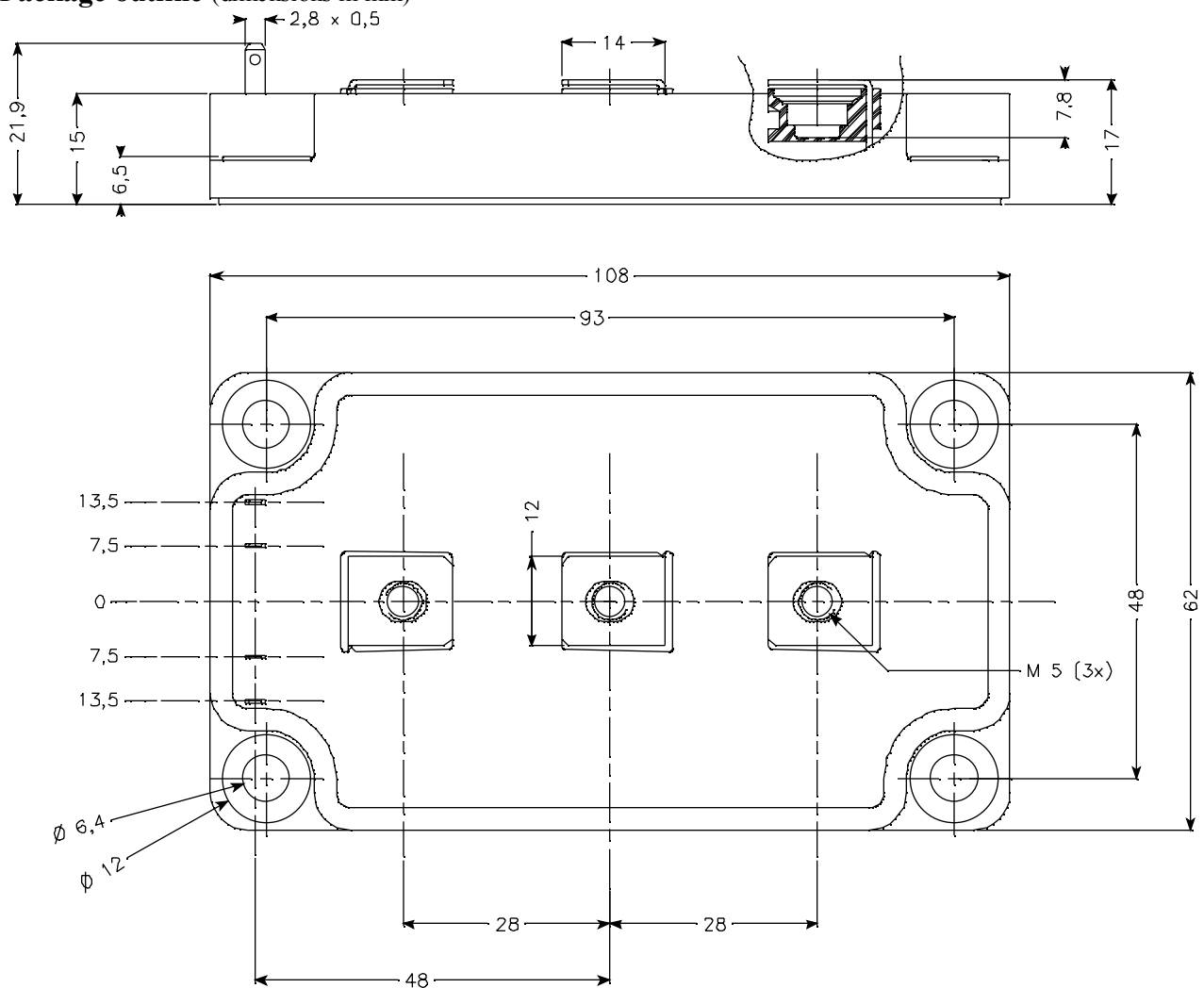
Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage		1700			V
I_{RM}	Maximum Reverse Leakage Current	$V_R = 1700\text{V}$	$T_j = 25^\circ\text{C}$		500	μA
			$T_j = 125^\circ\text{C}$		750	
$I_{F(AV)}$	Maximum Average Forward Current	50% duty cycle	$T_c = 80^\circ\text{C}$	225		A
V_F	Diode Forward Voltage	$I_F = 225\text{A}$	$T_j = 25^\circ\text{C}$	1.8	2.2	V
			$T_j = 125^\circ\text{C}$	1.9		
t_{rr}	Reverse Recovery Time	$I_F = 225\text{A}$ $V_R = 900\text{V}$	$T_j = 25^\circ\text{C}$	385		ns
			$T_j = 125^\circ\text{C}$	490		
Q_{rr}	Reverse Recovery Charge	$di/dt = 2400\text{A}/\mu\text{s}$	$T_j = 25^\circ\text{C}$	60		μC
			$T_j = 125^\circ\text{C}$	96		

Thermal and package characteristics

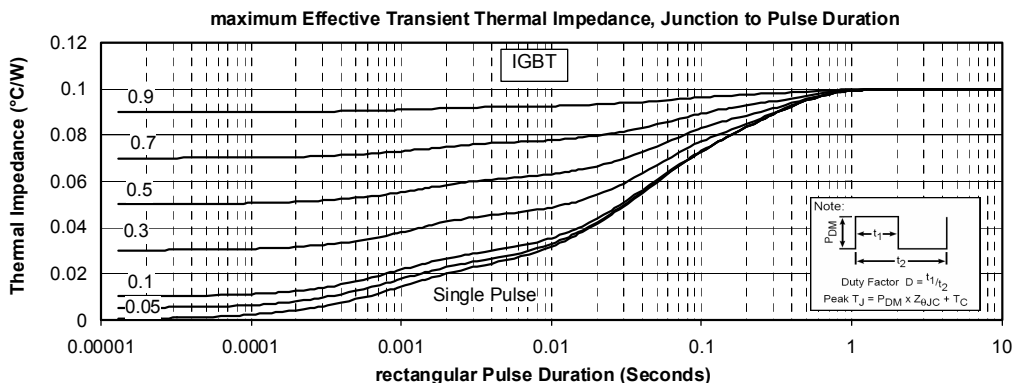
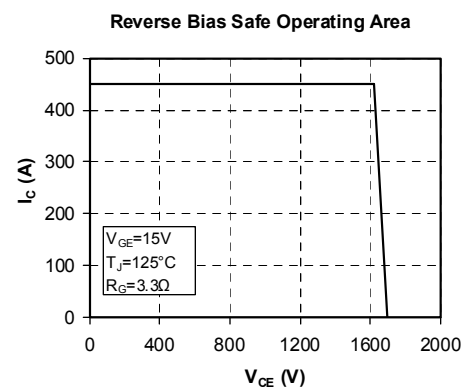
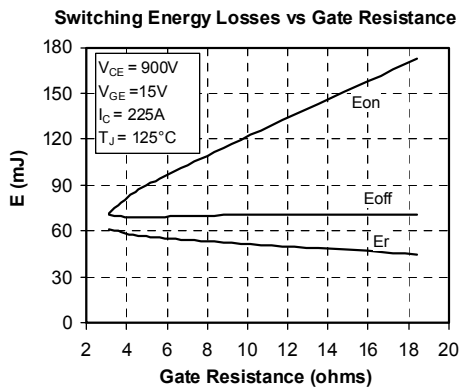
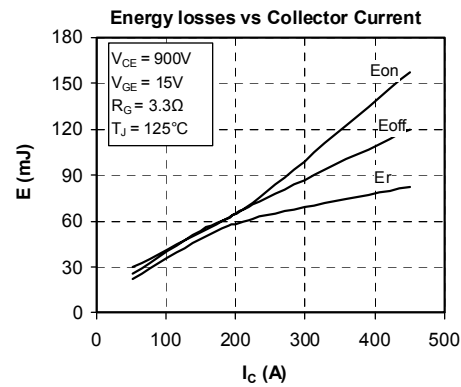
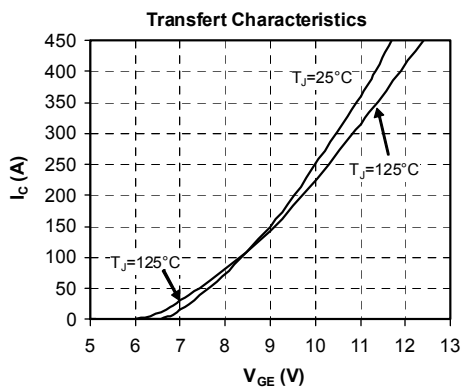
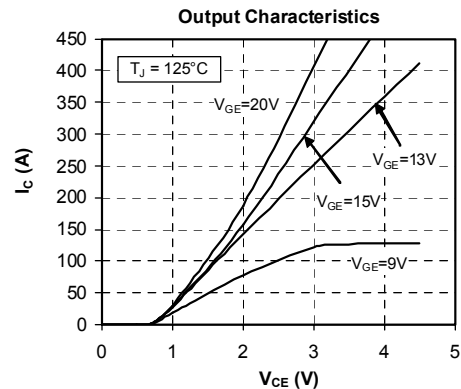
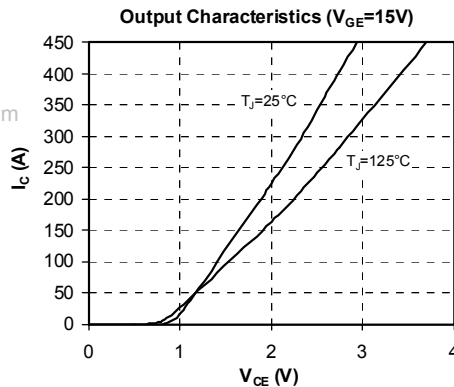
Symbol	Characteristic			Min	Typ	Max	Unit
R _{thJC}	Junction to Case			IGBT		0.1	°C/W
				Diode		0.18	
V _{ISO}	RMS Isolation Voltage, any terminal to case t=1 min, I isol<1mA, 50/60Hz			3400			V
T _J	Operating junction temperature range			-40		150	°C
T _{STG}	Storage Temperature Range			-40		125	
T _C	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	
Wt	Package Weight					280	g

Package outline (dimensions in mm)

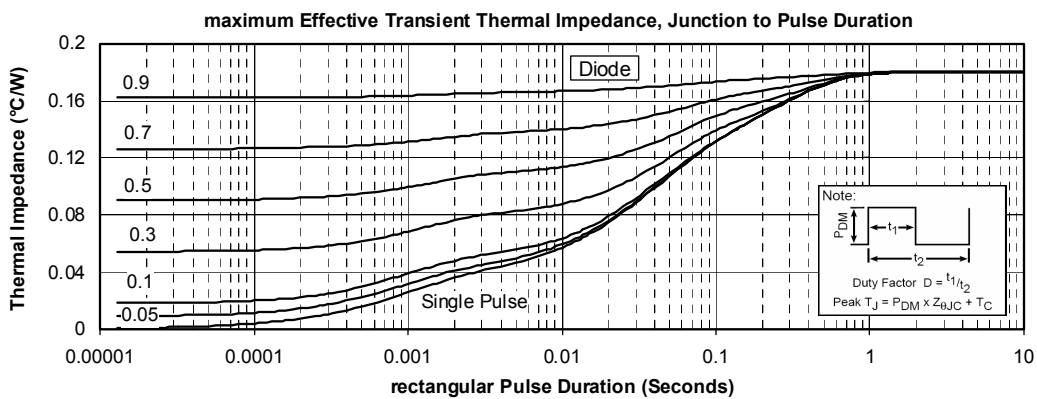
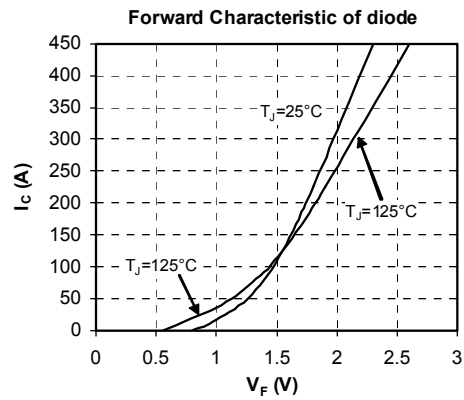
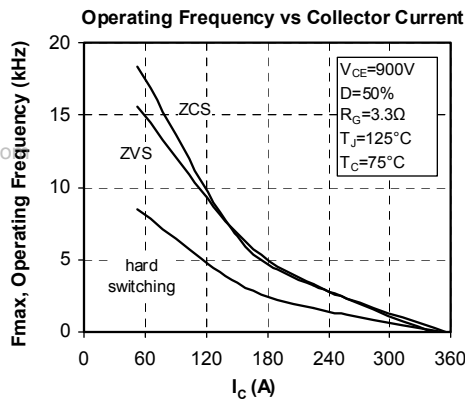


Typical Performance Curve

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